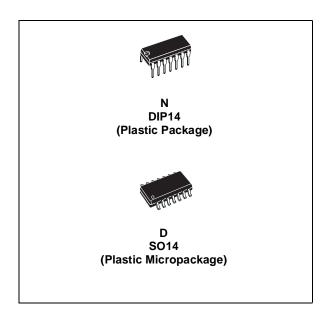


### TL074 TL074A - TL074B

### LOW NOISE J-FET QUAD OPERATIONAL AMPLIFIERS

- WIDE COMMON-MODE (UP TO V<sub>CC</sub><sup>+</sup>) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- LOW NOISE  $e_n = 15 \text{nV}/\sqrt{\text{Hz}}$  (typ)
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- LOW HARMONIC DISTORTION : 0.01% (typ)
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : 13V/µs (typ)



#### **DESCRIPTION**

The TL074, TL074A and TL074B are high speed J–FET input quad operational amplifiers incorporating well matched, high voltage J–FET and bipolar transistors in a monolithic integrated circuit.

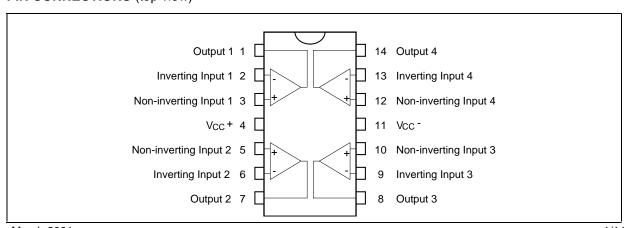
The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

#### **ORDER CODE**

Part Number	Temperature Range	Package						
Part Number	Temperature Kange	N	D					
TL074M/AM/BM	-55°C, +125°C	•	•					
TL074I/AI/BI	-40°C, +105°C	•	•					
TL074C/AC/BC	0°C, +70°C	•	•					
Example: TL074IN								

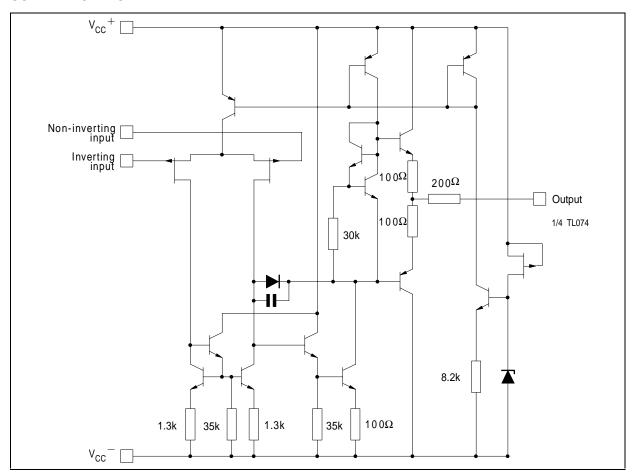
N = Dual in Line Package (DIP)
D = Small Outline Package (SO) - also available in Tape & Reel (DT)

#### **PIN CONNECTIONS** (top view)



March 2001 1/11

#### **SCHEMATIC DIAGRAM**



### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	TL074M, AM, BM	TL074I, AI, BI	TL074C, AC, BC	Unit		
V <sub>CC</sub>	Supply voltage - note 1)	±18					
V <sub>i</sub>	Input Voltage - note <sup>2)</sup>		±15		<b>V</b>		
V <sub>id</sub>	Differential Input Voltage - note 3)	±30					
P <sub>tot</sub>	Power Dissipation	680					
	Output Short-circuit Duration - note 4)	Infinite					
T <sub>oper</sub>	Operating Free-air Temperature Range	-55 to +125 -40 to +105 0 to +70			°C		
T <sub>stg</sub>	Storage Temperature Range -65 to +150						

- All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V<sub>CC</sub><sup>+</sup> and V<sub>CC</sub>.
- 2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
- 3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded

### **ELECTRICAL CHARACTERISTICS**

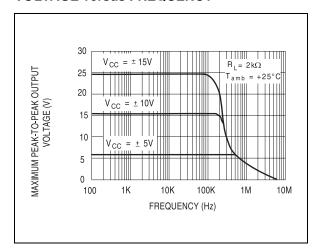
 $V_{CC} = \pm 15V$ ,  $T_{amb} = +25$ °C (unless otherwise specified)

Symbol	Parameter		TL074I,M,AC,AI,AM, BC,BI,BM			TL074C		
		Min.	Тур.	Max.	Min.	Тур.	Max.	
V <sub>io</sub>	Input Offset Voltage ( $R_s$ = 50 $\Omega$ ) $T_{amb}$ = +25°C $TL074$ $TL074A$ $TL074B$ $T_{min} \le T_{amb} \le T_{max}$ $TL074$ $TL074A$ $TL074A$ $TL074B$		3 3 1	10 6 3 13 7 5		3	10	mV
DV <sub>io</sub>	Input Offset Voltage Drift		10			10		μV/°C
l <sub>io</sub>	Input Offset Current - note $^{1)}$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		5	100 4		5	100 10	pA nA
l <sub>ib</sub>	Input Bias Current -note 1 $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	200 20		30	200 20	pA nA
$A_{vd}$	Large Signal Voltage Gain $(R_L = 2k\Omega, V_0 = \pm 10V)$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio ( $R_S = 50\Omega$ ) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
I <sub>CC</sub>	Supply Current, no load, per amplifier $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
$V_{\text{icm}}$	Input Common Mode Voltage Range	±11	+15 -12		±11	+15 -12		V
CMR	Common Mode Rejection Ratio ( $R_S = 50\Omega$ ) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
I <sub>os</sub>	Output Short-circuit Current $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	10 10	40	60 60	10 10	40	60 60	mA
±V <sub>opp</sub>	$\begin{array}{ll} \text{Output Voltage Swing} \\ T_{amb} = +25^{\circ}\text{C} & \text{RL} = 2k\Omega \\ & \text{RL} = 10k\Omega \\ T_{min} \leq T_{amb} \leq T_{max} & \text{RL} = 2k\Omega \\ & \text{RL} = 10k\Omega \end{array}$	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate ( $T_{amb}$ = +25°C) $V_{in}$ = 10V, $R_L$ = 2k $\Omega$ , $C_L$ = 100pF, unity gain	8	13		8	13		V/µs
t <sub>r</sub>	Rise Time ( $T_{amb} = +25^{\circ}C$ ) $V_{in} = 20$ mV, $R_L = 2$ k $\Omega$ , $C_L = 100$ pF, unity gain		0.1			0.1		μs
K <sub>ov</sub>	Overshoot ( $T_{amb}$ = +25°C) $V_{in}$ = 20mV, $R_L$ = 2k $\Omega$ , $C_L$ = 100pF, unity gain		10			10		%
GBP	Gain Bandwidth Product ( $T_{amb} = +25^{\circ}C$ ) $V_{in} = 10 \text{mV}, R_L = 2 \text{k}\Omega, C_L = 100 \text{pF}, f= 100 \text{kHz}$	2	3		2	3		MHz
R <sub>i</sub>	Input Resistance		10 <sup>12</sup>			10 <sup>12</sup>		Ω

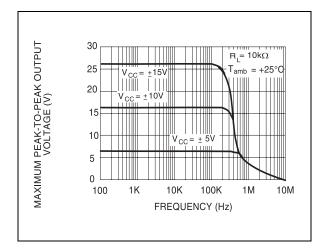
Symbol	Parameter	TL074I,M,AC,AI,AM, BC,BI,BM			TL074C			Unit
		Min.	Тур.	Max.	Min.	Тур.	Max.	
THD	Total Harmonic Distortion ( $T_{amb}$ = +25°C) f= 1kHz, $R_L$ = 2k $\Omega$ , $C_L$ = 100pF, $A_V$ = 20dB, $V_O$ = 2 $V_{pp}$		0.01			0.01		%
e <sub>n</sub>	Equivalent Input Noise Voltage $R_S = 100\Omega$ , $f = 1KHz$		15			15		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
Øm	Phase Margin		45			45		degrees
V <sub>01</sub> /V <sub>02</sub>	Channel separation $A_V = 100$		120			120		dB

<sup>1.</sup> The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature.

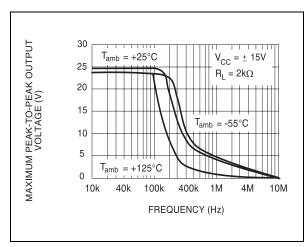
## MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



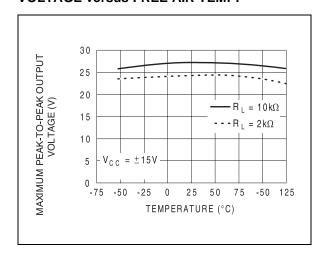
## MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



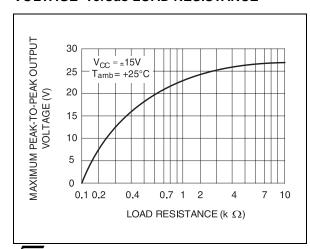
## MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



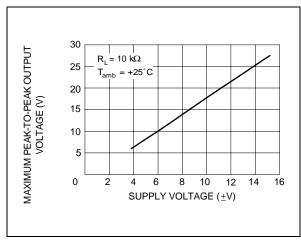
## MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREE AIR TEMP.



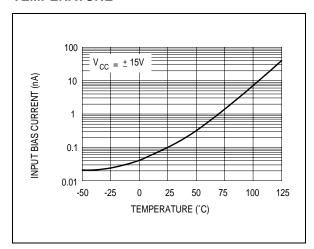
# MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus LOAD RESISTANCE



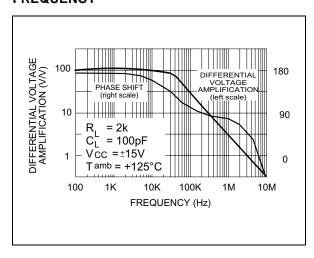
# MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus SUPPLY VOLTAGE



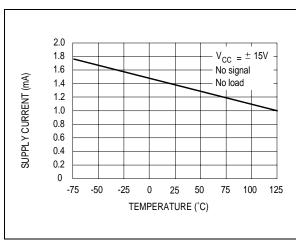
### INPUT BIAS CURRENT versus FREE AIR TEMPERATURE



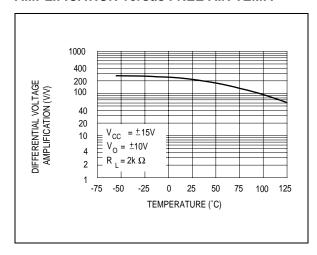
### LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



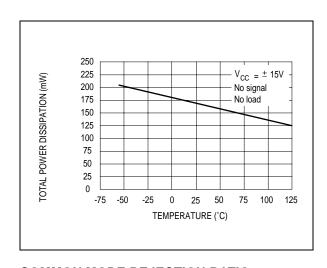
## SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE



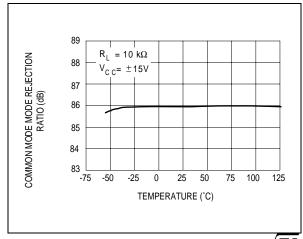
### LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION versus FREE AIR TEMP.



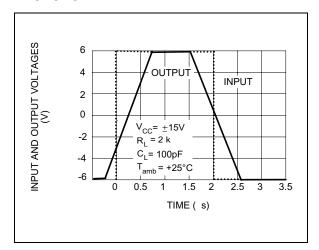
## TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE



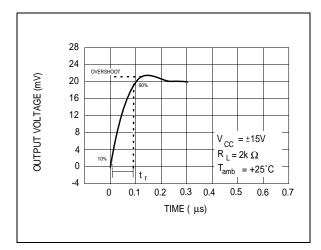
## COMMON MODE REJECTION RATIO versus FREE AIR TEMPERATURE



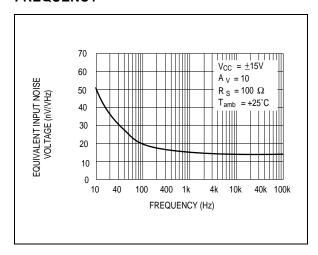
## VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



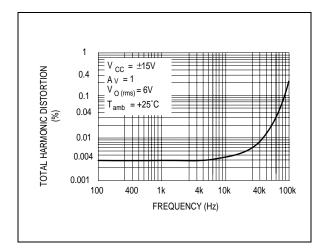
#### **OUTPUT VOLTAGE versus ELAPSED TIME**



## EQUIVALENT INPUT NOISE VOLTAGE versus FREQUENCY



## TOTAL HARMONIC DISTORTION versus FREQUENCY



### PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

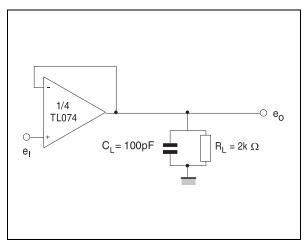
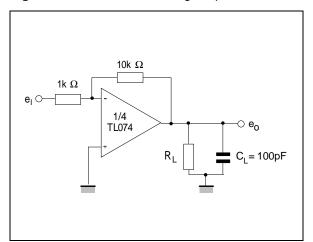
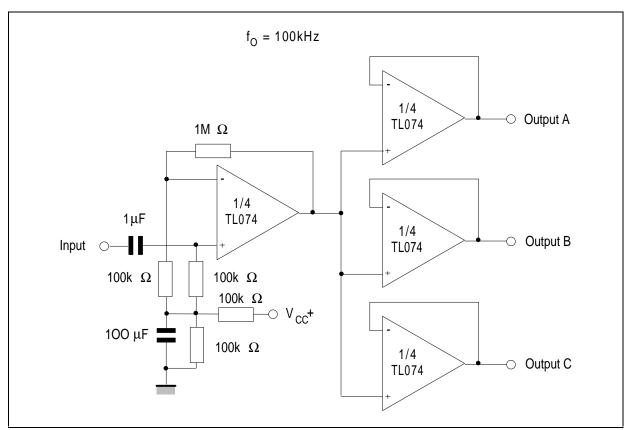


Figure 2 : Gain-of-10 Inverting Amplifier



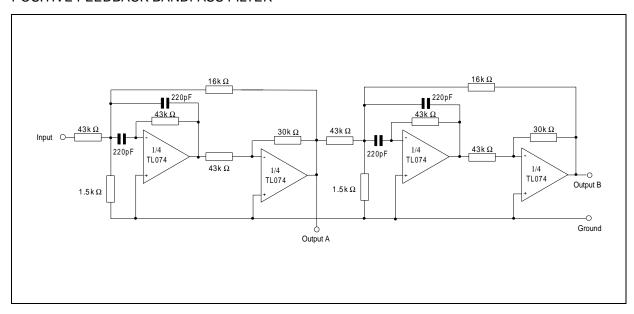
### **TYPICAL APPLICATIONS**

AUDIO DISTRIBUTION AMPLIFIER

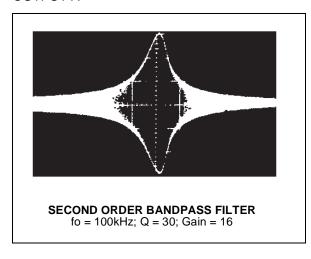


### **TYPICAL APPLICATIONS** (continued)

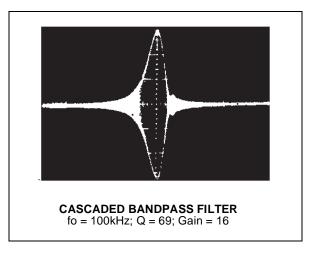
### POSITIVE FEEDBACK BANDPASS FILTER



### **OUTPUT A**

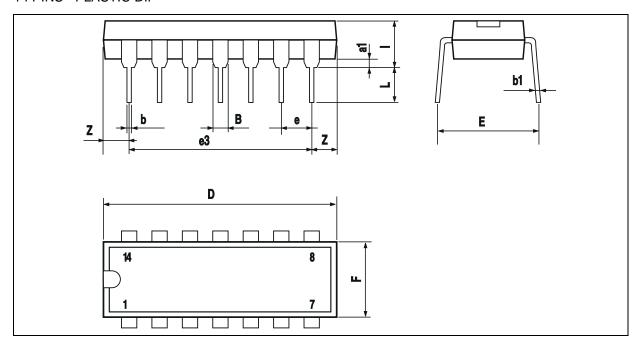


### **OUTPUT B**



### **PACKAGE MECHANICAL DATA**

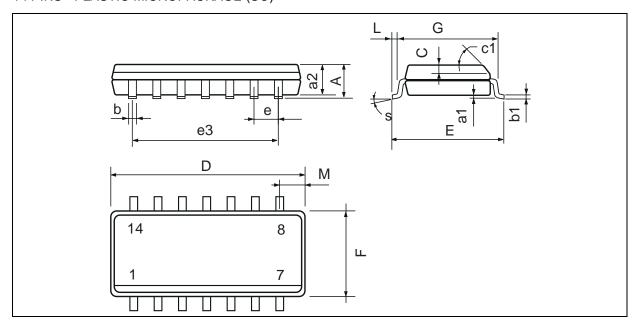
14 PINS - PLASTIC DIP



Dim	Millimeters			Inches				
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.		
a1	0.51			0.020				
В	1.39		1.65	0.055		0.065		
b		0.5			0.020			
b1		0.25			0.010			
D			20			0.787		
Е		8.5			0.335			
е		2.54			0.100			
e3		15.24			0.600			
F			7.1			0.280		
i			5.1			0.201		
L		3.3			0.130			
Z	1.27		2.54	0.050		0.100		

#### **PACKAGE MECHANICAL DATA**

14 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α			1.75			0.069		
a1	0.1		0.2	0.004		0.008		
a2			1.6			0.063		
b	0.35		0.46	0.014		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.020			
c1			45°	(typ.)				
D (1)	8.55		8.75	0.336		0.344		
E	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		7.62			0.300			
F (1)	3.8		4.0	0.150		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.020		0.050		
М			0.68			0.027		
S	8° (max.)							

Note: (1) D and F do not include mold flash or protrusions - Mold flash or protrusions shall not exceed 0.15mm (.066 inc) ONLY FOR DATA BOOK.

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2001 STMicroelectronics - Printed in Italy - All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia - Malta - Morocco Singapore - Spain - Sweden - Switzerland - United Kingdom © http://www.st.com



This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.